

## SANYO Semiconductors DATA SHEET

N-Channel Silicon MOSFET

# **CPH3427**— General-Purpose Switching Device **Applications**

#### **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 4V drive.

#### **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

| Parameter                   | Symbol | Conditions   | Ratings     | Unit |
|-----------------------------|--------|--|-------------|------|
| Drain-to-Source Voltage     | VDSS   |  | 100         | V    |
| Gate-to-Source Voltage      | VGSS   |  | ±20         | V    |
| Drain Current (DC)          | ID     |  | 1           | Α    |
| Drain Current (Pulse)       | IDP    | PW≤10μs, duty cycle≤1%                                 | 4           | Α    |
| Allowable Power Dissipation | PD     | Mounted on a ceramic board (900mm <sup>2</sup> X0.8mm) | 1           | W    |
| Channel Temperature         | Tch    |  | 150         | °C   |
| Storage Temperature         | Tstg   |  | -55 to +150 | °C   |

#### Electrical Characteristics at Ta=25°C

| Parameter                                  | Symbol                | Conditions                                 |     | Ratings |     |      |
|--|-----------------------|--|-----|---------|-----|------|
|  |                       |  | min | typ     | max | Unit |
| Drain-to-Source Breakdown Voltage          | V(BR)DSS              | ID=1mA, VGS=0                              | 100 |         |     | V    |
| Zero-Gate Voltage Drain Current            | IDSS                  | V <sub>DS</sub> =100V, V <sub>GS</sub> =0  |     |         | 1   | μΑ   |
| Gate-to-Source Leakage Current             | IGSS                  | V <sub>GS</sub> =±16V, V <sub>DS</sub> =0  |     |         | ±10 | μΑ   |
| Cutoff Voltage                             | VGS(off)              | VDS=10V, ID=1mA                            | 1.2 |         | 2.6 | V    |
| Forward Transfer Admittance                | yfs                   | V <sub>DS</sub> =10V, I <sub>D</sub> =0.5A | 0.7 | 1.4     |     | S    |
| Static Drain-to-Source On-State Resistance | R <sub>DS</sub> (on)1 | I <sub>D</sub> =0.5A, V <sub>G</sub> S=10V |     | 480     | 630 | mΩ   |
|  | RDS(on)2              | ID=0.5A, VGS=4V                            |     | 580     | 810 | mΩ   |
| Input Capacitance                          | Ciss                  | V <sub>DS</sub> =20V, f=1MHz               |     | 240     |     | pF   |
| Output Capacitance                         | Coss                  | V <sub>DS</sub> =20V, f=1MHz               |     | 20      |     | pF   |
| Reverse Transfer Capacitance               | Crss                  | V <sub>DS</sub> =20V, f=1MHz               |     | 12      |     | pF   |
| Turn-ON Delay Time                         | t <sub>d</sub> (on)   | See specified Test Circuit.                |     | 8       |     | ns   |
| Rise Time                                  | t <sub>r</sub>        | See specified Test Circuit.                |     | 3       |     | ns   |
| Turn-OFF Delay Time                        | td(off)               | See specified Test Circuit.                |     | 30      |     | ns   |
| Fall Time                                  | tf                    | See specified Test Circuit.                |     | 11      |     | ns   |

Marking: ZC Continued on next page.

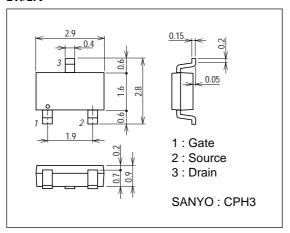
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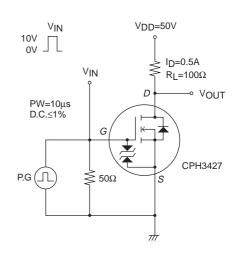
| Parameter                     | Symbol | Conditions   |     | Ratings |     |      |
|-------------------------------|--------|--|-----|---------|-----|------|
|                               | Symbol |  | min | typ     | max | Unit |
| Total Gate Charge             | Qg     | VDS=50V, VGS=10V, ID=1A  |     | 6.5     |     | nC   |
| Gate-to-Source Charge         | Qgs    | V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =1A |     | 1.1     |     | nC   |
| Gate-to-Drain "Miller" Charge | Qgd    | V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =1A |     | 1.1     |     | nC   |
| Diode Forward Voltage         | VSD    | IS=1A, VGS=0   |     | 0.82    | 1.2 | V    |

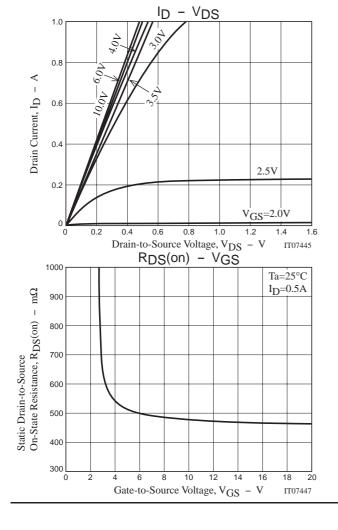
#### **Package Dimensions**

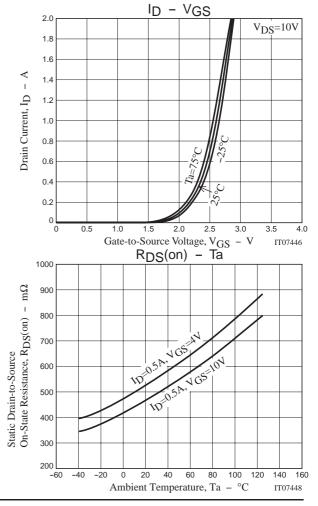
unit : mm 2152A

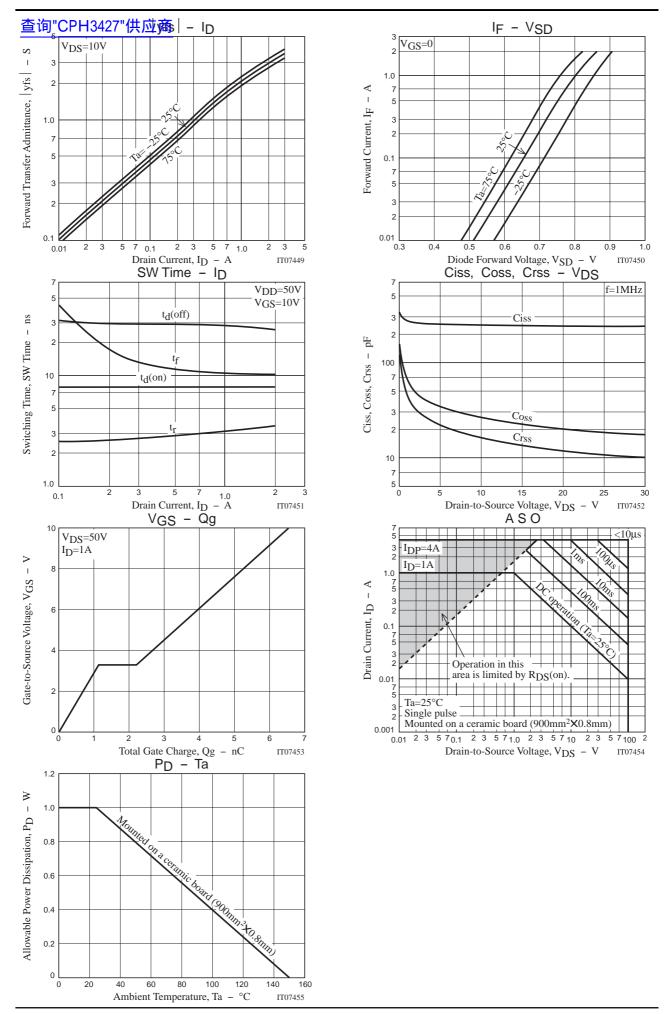


#### **Switching Time Test Circuit**









### 查询"CPH3427"供应商

Note on usage : Since the CPH3427 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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